NSN 5961-01-261-5374

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View Online at https://aerobasegroup.com/nsn/5961-01-261-5374 **Inclosure Material:** Plastic **Overall Length:** 0.185 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.165 inches **Overall Width:** 0.205 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage, dc and 40.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 310.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 60.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 3 uninsulated wire lead

Unit Of Measure:

Shelf Life:

Demilitarization:

Specification Data:

81349-mil-s-19500/530 government specification

No

N/a

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